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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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MODIFIED PTO/SB/08a (09-08)
10/559,615
December 2, 2005
Youichi NANBA
1795
Tony Sheng Hsiang CHUO
Q76011

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	MODIFIED PTO/SB/08a (09-08)
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First Named Inventor	Youichi NANBA
Art Unit	1795
Examiner Name	Tony Sheng Hsiang CHUO
Attorney Docket Number	Q76011

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